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# SN74CBTLV16800 LOW-VOLTAGE 20-BIT FET BUS SWITCH WITH PRECHARGED OUTPUTS

SCDS045J-DECEMBER 1997-REVISED MARCH 2005

#### **FEATURES**

- Member of the Texas Instruments Widebus™
  Family
- 5-Ω Switch Connection Between Two Ports
- Rail-to-Rail Switching on Data I/O Ports
- I<sub>off</sub> Supports Partial-Power-Down Mode Operation
- B-Port Outputs Are Precharged by Bias Voltage to Minimize Signal Distortion During Live Insertion
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II
- ESD Protection Exceeds JESD 22
  - 2000-V Human-Body Model (A114-A)
  - 200-V Machine Model (A115-A)

#### **DESCRIPTION/ORDERING INFORMATION**

The SN74CBTLV16800 provides 20 bits of high-speed bus switching. The low on-state resistance of the switch allows connections to be made with minimal propagation delay. The device also precharges the B port to a user-selectable bias voltage (BIASV) to minimize live-insertion noise.

The device is organized as dual 10-bit bus switches with separate output-enable  $(\overline{OE})$  inputs. It can be used as two 10-bit bus switches or one 20-bit bus switch. When  $\overline{OE}$  is low, the associated 10-bit bus switch is on, and port A is connected to port B. When  $\overline{OE}$  is high, the switch is open, the high-impedance state exists between the two ports, and port B is precharged to BIASV through the equivalent of a 10-k $\Omega$  resistor.

# DGG, DGV, OR DL PACKAGE (TOP VIEW)

		1 1		
BIASV [	1	$\cup$	48	] 1 <u>OE</u>
1A1 [	2		47	2 <mark>OE</mark>
1A2 [	3		46	] 1B1
1A3 [	4		45	1B2
1A4 [	5		44	] 1B3
1A5 [	6		43	] 1B4
1A6 [	7		42	] 1B5
GND [	8		41	] GND
1A7 [	9		40	] 1B6
1A8 [	10		39	] 1B7
1A9 [	11		38	] 1B8
1A10 [	12		37	] 1B9
2A1 [	13		36	] 1B10
2A2 [	14		35	] 2B1
v <sub>cc</sub> [	15		34	] 2B2
2A3 [	16		33	2B3
GND [	17		32	GND
2A4 [	18		31	2B4
2A5 [	19		30	] 2B5
2A6 [	20		29	2B6
2A7 [	21		28	2B7
2A8 🛚	22		27	2B8
2A9 [	23		26	] 2B9
2A10 [	24		25	2B10

This device is fully specified for partial-power-down applications using I<sub>off</sub>. The I<sub>off</sub> feature ensures that damaging current will not backflow through the device when it is powered down. The device has isolation during power off.

To ensure the high-impedance state during power up or power down,  $\overline{OE}$  should be tied to  $V_{CC}$  through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

#### ORDERING INFORMATION

T <sub>A</sub>	PACKAGE <sup>(1)</sup>		ORDERABLE PART NUMBER	TOP-SIDE MARKING	
	SSOP – DL	Tube	SN74CBTLV16800DL	- CBTLV16800	
4000 +- 0500	330P – DL	Tape and reel	SN74CBTLV16800DLR		
-40°C to 85°C	TSSOP - DGG	Tape and reel	SN74CBTLV16800GR	CBTLV16800	
	TVSOP - DGV	Tape and reel	SN74CBTLV16800VR	CN800	

 Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.

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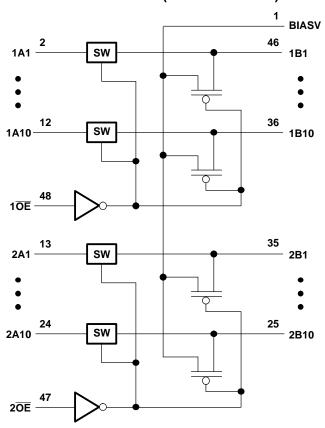
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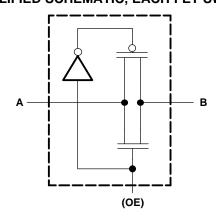
# FUNCTION TABLE (EACH 10-BIT BUS SWITCH)

INPUT OE	FUNCTION
L	A port = B port
Н	A port = Z B port = BIASV

## **LOGIC DIAGRAM (POSITIVE LOGIC)**



## SIMPLIFIED SCHEMATIC, EACH FET SWITCH





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# Absolute Maximum Ratings<sup>(1)</sup>

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
V <sub>CC</sub>	Supply voltage range		-0.5	4.6	V
BIASV	Bias voltage range		-0.5	4.6	V
VI	Input voltage range <sup>(2)</sup>		-0.5	4.6	V
	Continuous channel current			128	mA
I <sub>IK</sub>	Input clamp current	V <sub>I</sub> < 0		-50	mA
		DGG package		70	
$\theta_{JA}$	Package thermal impedance (3)	DGV package		58	°C/W
		DL package		63	
T <sub>stg</sub>	Storage temperature range		-65	150	°C

<sup>(1)</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- (2) The input and output negative-voltage ratings may be exceeded if the input and output clamp-current ratings are observed.
- (3) The package thermal impedance is calculated in accordance with JESD 51-7.

# **Recommended Operating Conditions**(1)

			MIN	MAX	UNIT
V <sub>CC</sub>	Supply voltage		2.3	3.6	V
BIASV	Bias voltage		1.3	$V_{CC}$	V
V <sub>IH</sub>	High level control input voltage	V <sub>CC</sub> = 2.3 V to 2.7 V	1.7		V
	High-level control input voltage	$V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$	2		
V <sub>IL</sub>	Low level control input voltage	V <sub>CC</sub> = 2.3 V to 2.7 V		0.7	V
	Low-level control input voltage	$V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$		0.8	
T <sub>A</sub>	Operating free-air temperature		-40	85	°C

<sup>(1)</sup> All unused control inputs of the device must be held at V<sub>CC</sub> or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.

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#### **Electrical Characteristics**

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER TEST CONDITIONS					MIN	TYP <sup>(1)</sup>	MAX	UNIT	
V <sub>IK</sub>		V <sub>CC</sub> = 3 V,	I <sub>I</sub> = -18 mA					-1.2	V
I		V <sub>CC</sub> = 3.6 V,	$V_I = V_{CC}$ or GND					±1	μΑ
I <sub>off</sub>	A port	$V_{CC} = 0$ ,	$V_{I}$ or $V_{O} = 0$ to 3.6 V					10	μΑ
Io		$V_{CC} = 3 V$ ,	BIASV = 2.4 V,	V <sub>O</sub> = 0,	$\overline{OE} = V_{CC}$		0.25		mA
$I_{CC}$		$V_{CC} = 3.6 \text{ V},$	$I_{O} = 0,$	$V_I = V_{CC}$ or GND				10	μΑ
$\Delta I_{CC}^{(2)}$	Control inputs	$V_{CC} = 3.6 \text{ V},$	One input at 3 V,	Other inputs at V <sub>C</sub>	c or GND			300	μΑ
C <sub>i</sub>	Control inputs	V <sub>I</sub> = 3 V or 0					4.5		pF
C <sub>io(OFF)</sub>		$V_0 = 3 \text{ V or } 0,$	Switch off,	BIASV = Open			6.5		pF
			V <sub>1</sub> = 0	I <sub>I</sub> = 64 mA			5	9	
		$V_{CC} = 2.3 \text{ V},$ TYP at $V_{CC} = 2.5 \text{ V}$	v <sub>1</sub> = 0	I <sub>I</sub> = 24 mA			5	9	
r <sub>on</sub> (3)			$V_1 = 1.7 V$ ,	I <sub>I</sub> = 15 mA			25	35	Ω
Ion V			V - 0	I <sub>I</sub> = 64 mA			5	7	52
		V <sub>CC</sub> = 3 V	$V_I = 0$	I <sub>I</sub> = 24 mA			5	7	
			$V_1 = 2.4 V,$	I <sub>I</sub> = 15 mA			8	15	

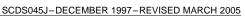
### **Switching Characteristics**

over recommended operating free-air temperature range (unless otherwise noted) (see Figure 1)

PARAMETER	TEST	FROM	TO (OUTPUT)	V <sub>CC</sub> = 2.5 V ± 0.2 V		V <sub>CC</sub> = 3.3 V ± 0.3 V		UNIT
	CONDITIONS (INPUT) (OUTPUT)		MIN	MAX	MIN	MAX		
t <sub>pd</sub> <sup>(1)</sup>		A or B	B or A		0.15		0.25	ns
t <sub>PZH</sub>	BIASV = GND	ŌĒ	A or D	2.9	7.7	2.2	5.5	20
t <sub>PZL</sub>	BIASV = 3 V	OE .	A or B	2.8	6.4	2.1	5.3	ns
t <sub>PHZ</sub>	BIASV = GND	ŌĒ	A or B	1.4	6.8	2.6	7.6	20
t <sub>PLZ</sub>	BIASV = 3 V	J OE	AUID	1.3	4.2	1.5	5.1	ns

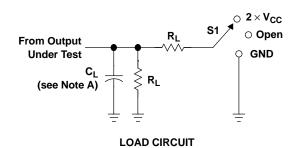
The propagation delay is the calculated RC time constant of the typical on-state resistance of the switch and the specified load capacitance, when driven by an ideal voltage source (zero output impedance).

All typical values are at  $V_{CC} = 3.3 \text{ V}$  (unless otherwise noted),  $T_A = 25^{\circ}\text{C}$ . This is the increase in supply current for each input that is at the specified voltage level, rather than  $V_{CC}$  or GND. Measured by the voltage drop between the A and B terminals at the indicated current through the switch. On-state resistance is determined by the lower of the voltages of the two (A or B) terminals.



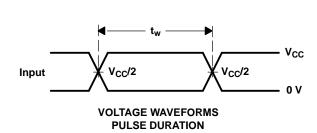


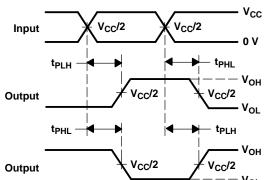
#### PARAMETER MEASUREMENT INFORMATION

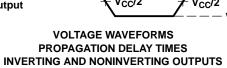


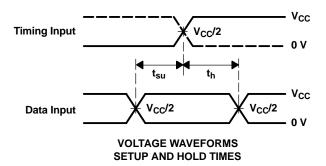
TEST	S1
t <sub>PLH</sub> /t <sub>PHL</sub>	Open
t <sub>PLZ</sub> /t <sub>PZL</sub>	2×V <sub>CC</sub>
t <sub>PHZ</sub> /t <sub>PZH</sub>	GND

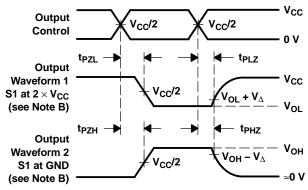
V <sub>CC</sub>	CL	R <sub>L</sub>	$\mathbf{V}_{\!\Delta}$
2.5 V $\pm$ 0.2 V	30 pF	500 Ω	0.15 V
3.3 V $\pm$ 0.3 V	50 pF	<b>500</b> Ω	0.3 V











VOLTAGE WAVEFORMS ENABLE AND DISABLE TIMES LOW- AND HIGH-LEVEL ENABLING

- NOTES: A. C<sub>L</sub> includes probe and jig capacitance.
  - B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
  - C. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  10 MHz,  $Z_O = 50 \Omega$ ,  $t_r \leq 2$  ns,  $t_f \leq 2$  ns.
  - D. The outputs are measured one at a time, with one transition per measurement.
  - E. t<sub>PLZ</sub> and t<sub>PHZ</sub> are the same as t<sub>dis</sub>.
  - F. t<sub>PZL</sub> and t<sub>PZH</sub> are the same as t<sub>en</sub>.
  - G. t<sub>PLH</sub> and t<sub>PHL</sub> are the same as t<sub>pd</sub>.
  - H. All parameters and waveforms are not applicable to all devices.

Figure 1. Load Circuit and Voltage Waveforms





i.com 24-Feb-2006

#### PACKAGING INFORMATION

Orderable Device	Status <sup>(1)</sup>	Package Type	Package Drawing	Pins	Package Qty	e Eco Plan <sup>(2)</sup>	Lead/Ball Finish	MSL Peak Temp <sup>(3)</sup>
74CBTLV16800DLG4	ACTIVE	SSOP	DL	48	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
74CBTLV16800DLRG4	ACTIVE	SSOP	DL	48	1000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
74CBTLV16800GRE4	ACTIVE	TSSOP	DGG	48	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
74CBTLV16800VRE4	ACTIVE	TVSOP	DGV	48	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74CBTLV16800DL	ACTIVE	SSOP	DL	48	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74CBTLV16800DLR	ACTIVE	SSOP	DL	48	1000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74CBTLV16800GR	ACTIVE	TSSOP	DGG	48	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74CBTLV16800VR	ACTIVE	TVSOP	DGV	48	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM

<sup>(1)</sup> The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

**NRND:** Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

**Pb-Free** (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

**Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

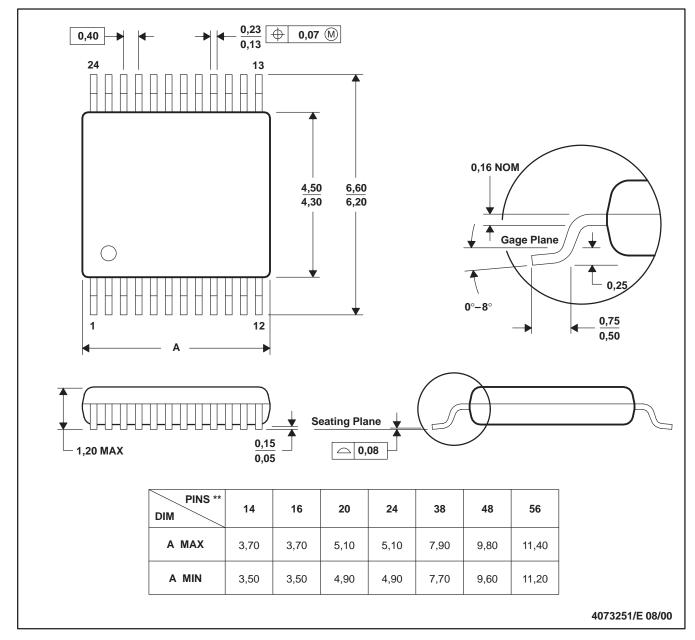
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## DGV (R-PDSO-G\*\*)

#### **24 PINS SHOWN**

#### **PLASTIC SMALL-OUTLINE**



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15 per side.

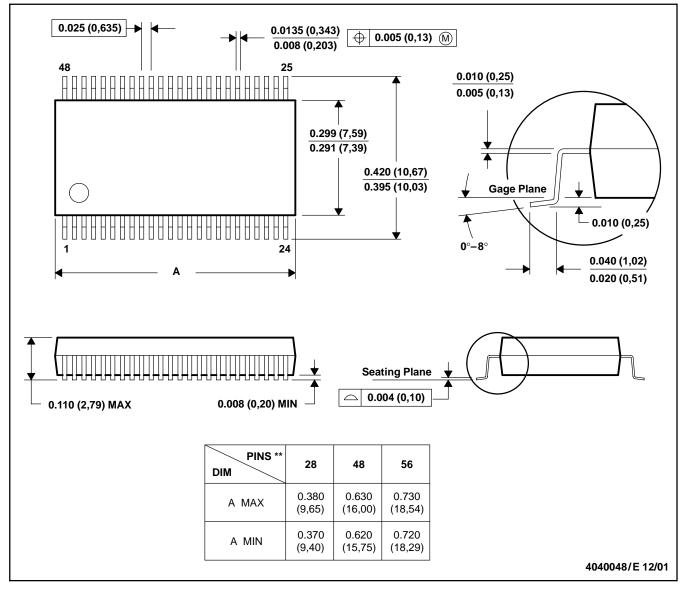
D. Falls within JEDEC: 24/48 Pins – MO-153 14/16/20/56 Pins – MO-194



### DL (R-PDSO-G\*\*)

#### **48 PINS SHOWN**

#### PLASTIC SMALL-OUTLINE PACKAGE



NOTES: A. All linear dimensions are in inches (millimeters).

B. This drawing is subject to change without notice.

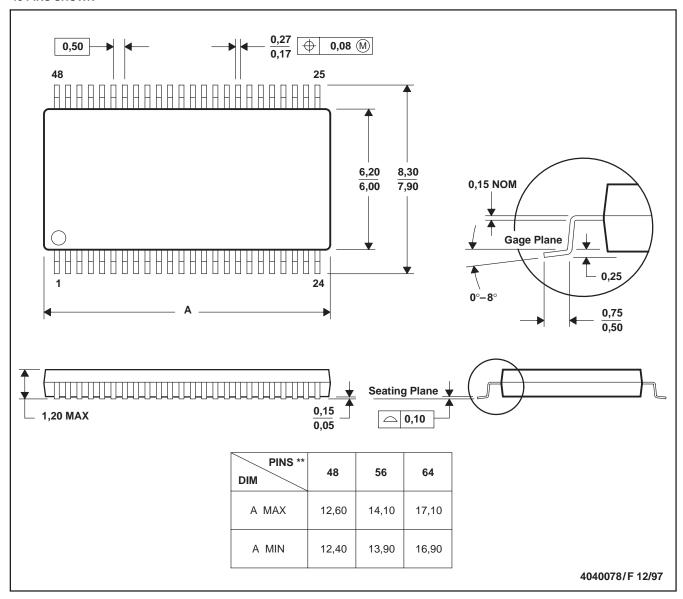
C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).

D. Falls within JEDEC MO-118

## DGG (R-PDSO-G\*\*)

## PLASTIC SMALL-OUTLINE PACKAGE

#### **48 PINS SHOWN**



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold protrusion not to exceed 0,15.

D. Falls within JEDEC MO-153

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